查询MC1488供应商

捷多邦,专业PCB打样**加C1488)**時**5月88**, SN75188 QUADRUPLE LINE DRIVERS

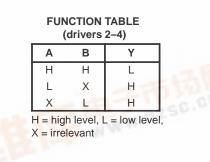
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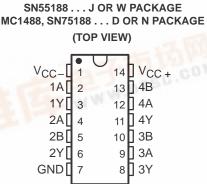
- Meet or Exceed the Requirements of ANSI EIA/TIA-232-E and ITU Recommendation V.28
- Designed to Be Interchangeable With Motorola MC1488
- Current-Limited Output: 10 mA Typical
- Power-Off Output Impedance: 300 Ω
 Minimum
- Slew Rate Control by Load Capacitor
- Flexible Supply Voltage Range
- Input Compatible With Most TTL Circuits

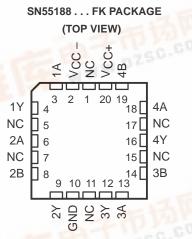
description

The MC1488, SN55188, and SN75188 are monolithic quadruple line drivers designed to interface data terminal equipment with data communications equipment in conformance with ANSI EIA/TIA-232-E using a diode in series with each supply-voltage terminal as shown under typical applications.

The SN55188 is characterized for operation over the full military temperature range of -55°C to 125°C. The MC1488 and SN75188 are characterized for operation from 0°C to 70°C.







NC – No internal connection

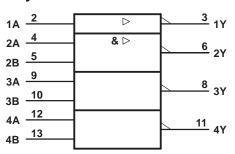


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logic symbol[†]

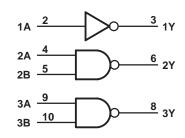


⁺ This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

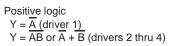
Pin numbers shown are for the D and N packages.

schematic (each driver)

logic diagram (positive logic)







To Other Drivers VCC+ **8.2 k**Ω **6.2 k**Ω Input(s) **70** Ω **300** Ω Output **3.6 k**Ω GND To Other Drivers ≷ **3.7 k**Ω **70** Ω V_{CC}-To Other Drivers

Resistor values shown are nominal.



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absolute maximum ratings over operating free-air temperature (unless otherwise noted)[†]

Supply voltage, V _{CC+} at (or below) 25°C free-air temperature (see Notes 1 and 2)
Input voltage, V ₁
Output voltage, V _O
Continuous total power dissipation (see Note 2) See Dissipation Rating Table
Operating free-air temperature range, T _A : SN55188
MC1488, SN75188
Storage temperature range, T _{stg} 65°C to 150°C
Case temperature for 60 seconds, FK package
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds: D or N package
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds: J or W package

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values are with respect to the network ground terminal.

2. For operation above 25°C free-air temperature, refer to the maximum supply voltage curve, Figure 6. In the FK and J packages, SN55188 chips are alloy mounted.

	DISSIPATION RATING TABLE										
PACKAGE	$T_A \le 25^{\circ}C$ POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 125°C POWER RATING							
D	950 mW	7.6 mW/°C	608 mW	-							
FK	1375 mW	11.0 mW/°C	880 mW	275 mW							
J	1375 mW	11.0 mW/°C	880 mW	275 mW							
N	1150 mW	9.2 mW/°C	736 mW	-							
W	1000 mW	8.0 mW/°C	640 mW	200 mW							

DISSIPATION RATING TABLE

recommended operating conditions

	SN55188			MC1488, SN75188			UNIT
	MIN	NOM	MAX	MIN	NOM	MAX	UNIT
Supply voltage, V _{CC+}	7.5	9	15	7.5	9	15	V
Supply voltage, V _{CC} _	-7.5	-9	-15	-7.5	-9	-15	V
High-level input voltage, V _{IH}	1.9			1.9			V
Low-level input voltage, VIL			0.8			0.8	V
Operating free-air temperature, T _A	-55		125	0		70	°C



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electrical characteristics over operating free-air temperature range, $V_{CC\pm}$ = \pm 9 V (unless otherwise noted)

			SN55188			MC1488, SN75188					
PARAMETER		TEST CONDITIONS		MIN	TYP†	MAX	MIN	TYP [†]	MAX	UNIT	
V _{OH}	High-level output voltage	$V_{IL} = 0.8 V,$ $R_L = 3 k\Omega$	V _{CC+} = 9 V, V _{CC-} = -9 V	6	7		6	7		V	
			$V_{CC+} = 13.2 V,$ $V_{CC-} = -13.2 V$	9	10.5		9	10.5			
V _{OL}	Low-level output voltage	V _{IH} = 1.9 V, R _L = 3 kΩ	V _{CC+} = 9 V, V _{CC-} = -9 V		-7‡	-6		-7	-6	V	
			$V_{CC+} = 13.2 V,$ $V_{CC-} = -13.2 V$		-10.5‡	-9		-10.5	-9 V	v	
Iн	High-level input current	V _I = 5 V				10			10	μΑ	
۱ _{IL}	Low-level input current	V _I = 0			-1	-1.6		-1	-1.6	mA	
IOS(H)	Short-circuit output current at high level§	V _I = 0.8 V,	V _O = 0	-4.6	-9	-13.5	-6	-9	-12	mA	
IOS(L)	Short-circuit output current at low level§	V _I = 1.9 V,	$V_{O} = 0$	4.6	9	13.5	6	9	12	mA	
r _o	Output resistance, power off	$V_{CC+} = 0,$ $V_{O} = -2 V \text{ to } 2 V$	$V_{CC-} = 0,$	300			300			Ω	
	Supply current from VCC+	V _{CC+} = 9 V, No load	All inputs at 1.9 V		15	20		15	20	mA	
			All inputs at 0.8 V		4.5	6		4.5	6		
100		V _{CC+} = 12 V, No load	All inputs at 1.9 V		19	25		19	25		
ICC+			All inputs at 0.8 V		5.5	7		5.5	7		
		$V_{CC+} = 15 V$, No load, $T_A = 25^{\circ}C$	All inputs at 1.9 V			34			34		
			All inputs at 0.8 V			12			12		
	Supply current from I _{CC} _	$V_{CC-} = -9 V$, No load	All inputs at 1.9 V		-13	-17		-13	-17	mA	
			All inputs at 0.8 V			-0.5			-0.015		
		$V_{CC-} = -12 V$, No load	All inputs at 1.9 V		-18	-23		-18	-23		
ICC-			All inputs at 0.8 V			-0.5		-	-0.015		
		$V_{CC-} = -15 \text{ V},$ No load, $T_A = 25^{\circ}\text{C}$	All inputs at 1.9 V			-34			-34		
			All inputs at 0.8 V			-2.5			-2.5		
PD	Total power dissipation	V _{CC+} = 9 V, No load	$V_{CC-} = -9 V,$			333			333		
		V _{CC+} = 12 V, No load	$V_{CC-} = -12 V,$			576			576	mW	

[†] All typical values are at $T_A = 25^{\circ}C$.

[‡] The algebraic convention, in which the less positive (more negative) limit is designated as minimum, is used in this data sheet for logic voltage levels only, e.g., if −6 V is a maximum, the typical value is a more negative voltage.

§ Not more than one output should be shorted at a time.



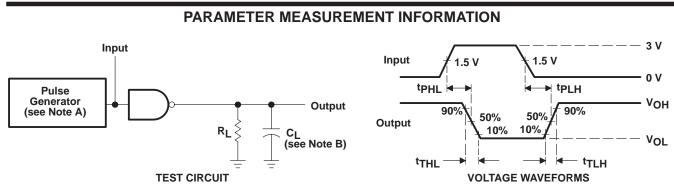
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switching characteristics, $V_{C\,C\pm}$ = ±9 V, T_A = 25°C

PARAMETER		TEST CON	MIN	TYP	MAX	UNIT	
^t PLH	Propagation delay time, low- to high-level output				220	350	ns
^t PHL	Propagation delay time, high- to low-level output	$R_L = 3 k\Omega$,	C _L = 15 pF,		100	175	ns
^t TLH	Transition time, low- to high-level $output^{\dagger}$	See Figure 1			55	100	ns
^t THL	Transition time, high- to low-level output †				45	75	ns
^t TLH	Transition time, low- to high-level output \ddagger	$R_L = 3 k\Omega$ to 7 k Ω ,	C _L = 2500 pF,		2.5		μs
^t THL	Transition time, high- to low-level output‡	See Figure 1			3.0		μs

[†] Measured between 10% and 90% points of output waveform.

[‡]Measured between 3 V and -3 V points on the output waveform (EIA/TIA-232-E conditions).

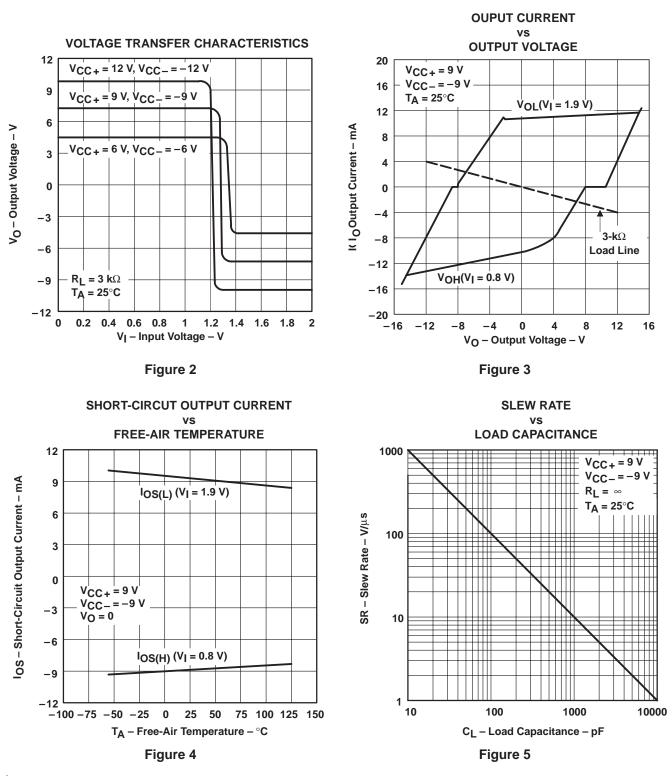


NOTES: A. The pulse generator has the following characteristics: $t_W = 0.5 \ \mu s$, PRR $\leq 1 \ MHz$, $Z_O = 50 \ \Omega$. B. CL includes probe and jig capacitance.

Figure 1. Test Circuit and Voltage Waveforms



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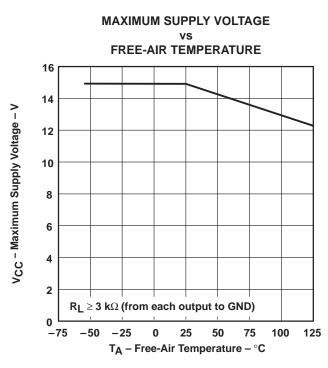


TYPICAL CHARACTERISTICS[†]

 † Data for temperatures below 0°C and above 70°C are applicable to SN55188 circuit only.



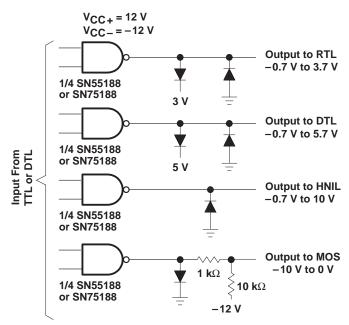
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THERMAL INFORMATION[†]

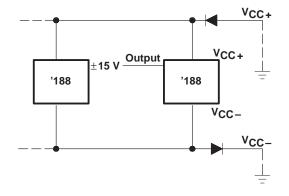
Figure 6

[†] Data for temperatures below 0°C and above 70°C are applicable to SN55188 circuit only.





APPLICATION INFORMATION



Diodes placed in series with the V_{CC+} and V_{CC-} leads will protect the SN55188/SN75188 in the fault condition in which the device outputs are shorted to $\pm\,15$ V and the power supplies are at low voltage and provide low-impedance paths to ground.

Figure 8. Power Supply Protection to Meet Power-Off Fault Conditions of ANSI EIA/TIA-232-E



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